



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

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LABORATORY GROWN DIAMOND REPORT

September 26, 2026

IGI Report Number

LG841674901

Description

LABORATORY GROWN DIAMOND

Shape and Cutting Style

ROUND BRILLIANT

Measurements

8.61 - 8.65 X 5.32 MM

GRADING RESULTS

Carat Weight

2.50 CARATS

Color Grade

E

Clarity Grade

VS 1

Cut Grade

EXCELLENT

ADDITIONAL GRADING INFORMATION

Polish

EXCELLENT

Symmetry

EXCELLENT

Fluorescence

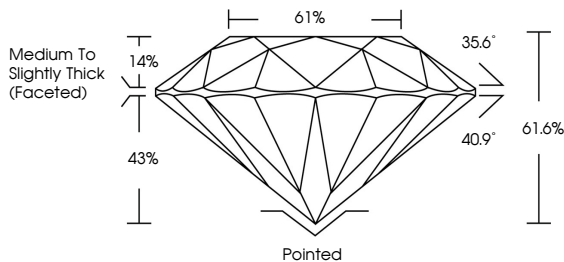
NONE

Inscription(s)

 LG841674901

Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process.
Type IIa

PROPORTIONS



Medium To Slightly Thick (Faceted)

61%

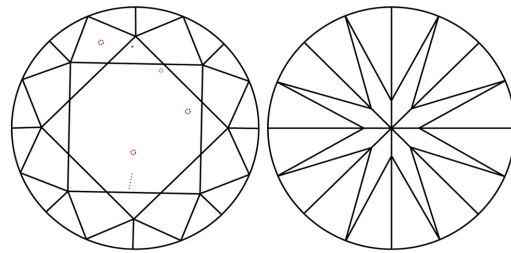
35.6°

40.9°

61.6%

Pointed

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.

Green symbols indicate external characteristics.

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL IF VVS¹⁻² VS¹⁻² SI¹⁻² I¹⁻³

Flawless Internally Flawless Very Very Slightly Included Very Slightly Included Slightly Included Included

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